arXiv:0806.2648v3 [cond-mat.supr-con] 21 Nov 2008

Transport and anisotropy in single-crystalline $SrFe_2As_2$ and $A_{0.6}K_{0.4}Fe_2As_2$ (A = Sr, Ba) superconductors

G. F. Chen, Z. Li, J. Dong, G. Li, W. Z. Hu, X. D.
Zhang, X. H. Song, P. Zheng, N. L. Wang, and J. L. Luo
Beijing National Laboratory for Condensed Matter Physics,
Institute of Physics, Chinese Academy of Sciences, Beijing 100190, China

Abstract

We have successfully grown high quality single crystals of $SrFe_2As_2$ and $A_{0.6}K_{0.4}Fe_2As_2$(A=Sr, Ba) using flux method. The resistivity, specific heat and Hall coefficient have been measured. For parent compound $SrFe_2As_2$, an anisotropic resistivity with ρ_c/ρ_{ab} as large as 130 is obtained at low temperatures. A sharp drop in both in-plane and out-plane resistivity due to the SDW instability is observed below 200 K. The angular dependence of in-plane magnetoresistance shows 2-fold symmetry with field rotating within ab plane below SDW transition temperature. This is consistent with a stripe-type spin ordering in SDW state. In K doped $A_{0.6}K_{0.4}Fe_2As_2$(A=Sr. Ba), the SDW instability is suppressed and the superconductivity appears with T_c above 35 K. The rather low anisotropy in upper critical field between H‖ab and H‖c indicates inter-plane coupling play an important role in hole doped Fe-based superconductors.

PACS numbers: 74.70.-b, 74.62.Bf, 74.25.Gz

The recent discovery of superconductivity with transition temperature T$_c$ ∼26 K in LaFeAsO$_{1-x}$F$_x$ has generated tremendous interest in scientific community[1]. Shortly after this discovery, the T$_c$ was raised to 41-55 K by replacing La by rare-earth Ce, Sm, Pr, Nd, etc, making those systems with T$_c$ exceeding 50 K.[2,3,4,5] The undoped quaternary compounds crystallize in a tetragonal ZrCusiAs-type structure, which consists of alternate stacking of edge-sharing Fe_2As_2 tetrahedral layers and La_2O_2 tetrahedral layers along c-axis. Very recently, superconductivity with T$_c$ up to 38 K was discovered in AFe_2As_2(A=Ba, Sr, Ca) upon K or Na-doping.[6,7,8,9,10] AFe_2As_2 compounds crystallize in a tetragonal $ThCr_2Si_2$-type structure with identical Fe_2As_2 tetrahedral layers as in LaFeAsO, but separated by single elemental A-layers. These compounds contain no oxygen in A layers. The simpler structure of AFe_2As_2 system makes it more suitable for research of intrinsic physical properties of Fe-based compounds.

Except for a relatively high transition temperature, the system displays many interesting properties. The existence of a spin-density-wave (SDW) instability in parent LaFeAsO[11] was indicated by specific heat, optical measurements and first principle calculations, and subsequently confirmed by neutron scattering,[12] NMR,[13] μsR,[14] and Mössbaure[15] spectroscopic measurements. The superconductivity only appears when SDW instability was suppressed by doping carriers or applying pressure. The competition between superconductivity and SDW instability was identified in other rare-earth substituted systems[2,16,17]. Besides the SDW instability, a structural distortion from tetragonal to monoclinic were also observed for both ReFeAsO(Re=rare earth) and AFe_2As_2 (A=Ba, Sr, Ca)[18,19,20,21,22,23]. The structural transition temperature were found to occur at slightly higher than SDW transition temperature in LaFeAsO[12], but the two transitions occur simultaneously in AFe_2As_2(A=Ba, Sr, Ca).[18,19,24] The band structure calculation and neutron scattering experiments indicated a stripe-type antiforremagnetic structure of Fe moments in SDW state in LaFeAsO.[11,12] In such a spin structure, a 4-fold spin rotation symmetry is broken and reduced to 2-fold. It is interesting to see if such a 2-fold symmetry could be observed in angular-dependent magneto-resistance measurements.

In this work, we present resistivity, specific heat and Hall coefficient measurements on single crystals $SrFe_2As_2$ and $A_{0.6}K_{0.4}Fe_2As_2$ (A=Sr, Ba). A large anisotropic resistivity with $\rho_c/\rho_{ab} \sim 130$ is observed for $SrFe_2As_2$. Below 200K, a sharp drop in both in-plane and out-plane resistivity due to the SDW instability is observed, similar to previously results on polycrystal samples[7]. Moreover, the angular-dependence of in-plane and out-plane magnetoresistance shows 2-fold symmetry with field rotating within ab plane below SDW transition temperature. The breaking of 4-fold rotation symmetry to 2-fold provides transport evidence for the formation of a stripe-type antiforremagnetic structure of Fe moments in SDW state. Moreover, the anisotropy of upper critical field for high quality single crystal $Sr_{0.6}K_{0.4}Fe_2As_2$ is investigated. The inter-layer coupling is relatively strong in superconducting samples.

The parent single crystals $SrFe_2As_2$ were prepared by the high temperature solution method using Sn as flux, similar to the procedure described in ref[21]. The superconducting crystals $A_{0.6}K_{0.4}Fe_2As_2$ (A=Sr, Ba) were prepared by the high temperature solution method using FeAs as flux. The starting materials of Sr or Ba, K, and FeAs in a ratio of 0.5:1:4 were put into an alumina crucible and sealed in welded Ta crucible under 1.6 atmosphere of argon. The Ta crucible were then sealed in an evacuated quartz ampoule and heated at 1150 $^\circ C$ for 5 hours and cooled slowly to 800 $^\circ C$ over 50 hours. The plate-like crystals with sizes up to 10mm×5m×0.5mm could be obtained after breaking the alumina crucible. Both scanning electron microscopy/energy dispersive x-ray (SEM/EDX) and induction-coupled plasma (ICP) analysis revealed that the elemental composition of the crystal is $A_{0.6\pm\delta}K_{0.4\mp\delta}Fe_2As_2$ (A=Sr, Ba) with $\delta \leq 0.02$. Figure 1(a) shows X-ray diffraction pattern of parent $SrFe_2As_2$ with the 00 ℓ reflections. The lattice constant c = 0.1239 nm was calculated from the higher order peaks, comparable to that of polycrystalline sample[7]. Figure 1(b) shows the EDX analysis of $Ba_{0.6}K_{0.4}Fe_2As_2$ crystal.

The in-plane resistivity was measured by the standard 4-probe method. The out-plane resistivity was measured using a typical method for layered materials as shown in inset of Fig. 2(b). The silver paste was used to cover almost all area of upper and lower side of the measured sample for two current leads, and leaves two small holes in the center of both sides for the voltage leads. Assuming that the current density is uniformly distributed throughout the cross section, the resistivity can then be measured with: ρ_c = R S /d, where R is the resistance, S is area of cross section and d is the thickness of the sample. The error comes mostly from the measurement of geometry factors. The ac magnetic susceptibility was measured with a modulation field in the amplitude of 10 Oe and a frequency of 333 Hz. The Hall coefficient measurement was done using a five-probe technique. The specific heat measurement was carried out using a thermal relaxation calorimeter. All these measurements were preformed down to 1.8K in a Physical Property Measurement System(PPMS)

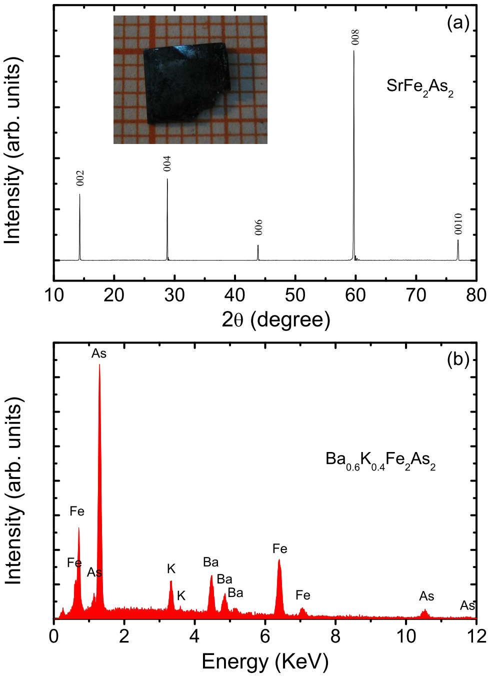

FIG. 1: (Color online) (a) Single crystal X-ray diffraction pattern for $SrFe_2As_2$. The inset shows the photograph of a $SrFe_2As_2$ single crystal (length scale 1 mm). (b) EDX analysis of $Ba_{0.6}K_{0.4}Fe_2As_2$ crystal.

of Quantum Design company.

Figure 2(a) shows the temperature dependence of in-plane resistivity ρ_{ab} in zero field and 8 T, and Fig. 2(b) shows the out-plane resistivity ρ_c for $SrFe_2As_2$ in zero field. They have similar T-dependent behavior and exhibit a strong anomaly at about 200 K: the resistivity drops steeply below this temperature. This is a characteristic feature related to SDW instability and a structural distortion in parent compounds of Fe-based high T_c superconductors.[11,12] The transition temperature is slightly lower than that observed in polycrystalline $SrFe_2As_2$ ($\sim$ 205 K). The anisotropic resistivity ρ_c/ρ_{ab} is found to be $\sim 130\pm65$ at 25 K. It is comparable with that of layered cuprates $YBa_2Cu_3O_{7-\delta}$.[25] From Fig.2(a), we find that the SDW transition temperature is insensitive to the applied field, however a large positive magnetoresistance is observed at low temperatures. At 10 K, the magnetoresistance $[\rho_{ab}(8T)\text{-}\rho_{ab}(0T)]/\rho_{ab}(0T)$ reaches as high as 25%. The behavior is similar to that observed in polycrystal LaFeAsO.[11]. The large positive magnetoresistance can be understood from

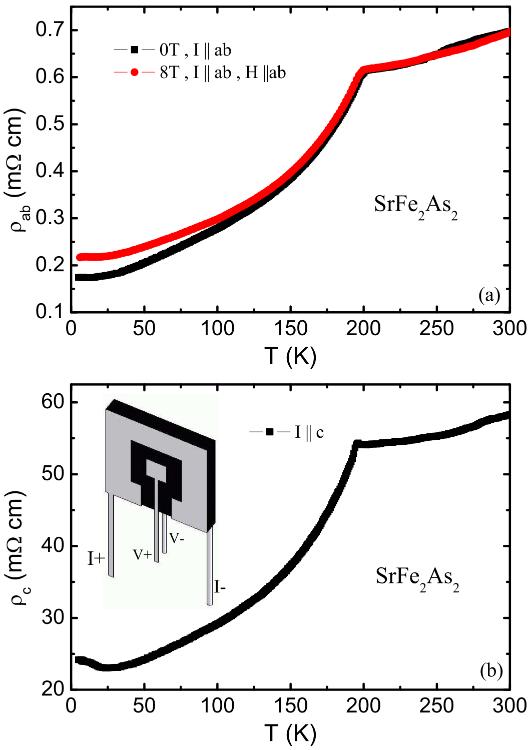

FIG. 2: (Color online) (a) The in-plane resistivity ρ_{ab} for $SrFe_2As_2$ in zero field and 8 T, respectively. (b) The out-plane resistivity ρ_c in zero field. The inset shows a sketch for how to measure ρ_c.

the suppression of SDW order by applied field and thus the spin scattering is enhanced.

In a system with strong coupling of charge carrier and background magnetism, angular-dependent-magnetoresistance(AMR) is a useful tool to detect the magnetic structure of background magnetism. AMR measurements have been successfully used in understanding the spin structure of slightly doped high T_c cuprates and charge ordering $Na_{0.5}CoO_2$ systems.[26,27] For this purpose, we measured the in-plane resistivity with magnetic field of 10 T rotating within the ab plane for $SrFe_2As_2$. Figure 3 shows AMR ($\Delta\rho(\theta) = \rho(\theta) - \rho(90^\circ)$) at 10, 30, 50, 100, 150 and 200 K, respectively. $\Delta\rho(\theta)$ shows a clear 2-fold oscillation below 200K. However, the 2-fold oscillation disappears at 200 K, a temperature just above T_{SDW}. Above T_{SDW}, the spin orientations of Fe moments are random so there is no angular dependent magnetoresistance arising from spin scattering. However below T_{SDW}, a large MR is observed at low temperature and it originates from the enhanced spin scattering while SDW order is suppressed in external magnetic field. Therefore the symmetry of the AMR oscillation reflect directly the symmetry of spin structure. The observation of 2-fold symmetry oscillations in $SrFe_2As_2$ in low temperatures indicates the stripe-type spin structure

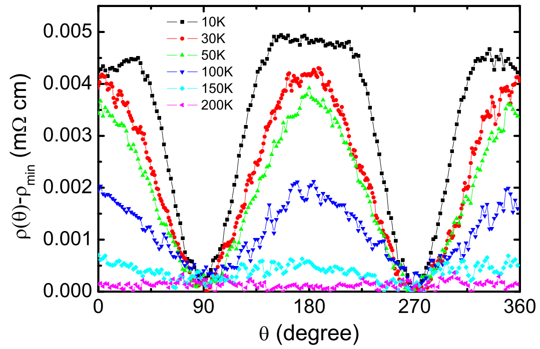

FIG. 3: (Color online) Angular dependence of in-plane magnetoresistance($\Delta\rho(\theta) = \rho(\theta) - \rho(90^\circ)$) at different temperatures in external magnetic field of 10T rotating within ab plane for $SrFe_2As_2$

of Fe moments in ground state. The recent neutron diffraction measurements on $SrFe_2As_2$ single crystals[24] and polycrystalline[28] indicate that the SDW transition is indeed presented in $SrFe_2As_2$ system below a transition temperature of $\sim$ 200-220 K. The stripe-type antiferromagnetic spin structure is found in the SDW state. Moreover, the angular-dependent magnetization measurement on $BaFe_2As_2$ crystal with field rotating within the ab plane also show a 2-fold symmetry of magnetization below SDW transition temperature[29], consistent with the AMR measurements on $SrFe_2As_2$ crystals. Therefore AMR can act as a probe for SDW order in these systems without having to wait for neutron beam time. Similar 2-fold symmetry oscillations of AMR has been observed in $Na_{0.5}CoO_2$ which was attributed to ordering of charge stripes.[27]

To get more information about the SDW and structural phase transition, we preformed specific heat and Hall resistivity measurement for $SrFe_2As_2$. Figure 4(a) shows the temperature dependence of specific heat C from 2 to 230 K. We can see clearly a sharp δ-function shape peak at about 200 K with $\Delta C \sim 185$ J/molK. This is a characteristic feature of a first-order phase transition. The transition temperature agrees well with that observed in resistivity measurement. The latent heat of the transition is estimated being 463±50 J/mol by integral the area of the specific heat data around the transition peak after subtracting the background. The background is estimated using a linear fit of the specific heat data above and below the transition. It worth noting that only one peak at around 200 K is observed in $SrFe_2As_2$, different from that of LaFeAsO where two subsequent peaks at 155 K and 143 K were observed in specific heat data corresponding to structural and SDW transition, respectively.[30] This suggests the structural transition and SDW transition occur at same temperature in $SrFe_2As_2$, similar to that observed in $BaFe_2As_2$.[18,19] At low temperatures, a good linear T^2 dependence of C/T is observed indicates that the specific heat C is mainly contributed by electrons and phonons [see inset Fig. 4(a)]. The fit yields the electronic coefficient γ=6.5 mJ/mol.K^2 and the Debye temperature $\theta_D = 245$ K. Note that the electronic coefficient is significantly smaller than the values obtained from the band structure calculations for non-magnetic state.[31] This can be explained that a partial energy gap is opened below SDW transition, the smaller experimental value here could be naturally accounted for by the gap formation which removes parts of the density of states below the phase transition. Compared with band calculation, similar smaller electronic specific heat coefficient was also observed in LaOFeAs due to gap opening originated from SDW instability.[11] In comparison, we also measured specific heat of superconducting crystal $Sr_{0.6}K_{0.4}Fe_2As_2$ prepared using FeAs as flux. It is found that no structural and SDW transition can be observed in specific heat data. Instead, a specific heat anomaly at a superconducting transition temperature with $T_c \sim 35.6$ K is observed. The specific heat jump $\Delta C/T_c$ is found to be $\sim$ 48 mJ/mol.K^2.

Hall coefficient R_H as a function of temperature between 20 and 300 K for $SrFe_2As_2$ is shown in Fig. 5. For comparison, R_H(T) for LaFeAsO is also shown in inset of Fig. 5. Above 200 K, the Hall coefficient is negative and nearly temperature independent for $SrFe_2As_2$, indicating conduction carriers are dominated by electrons. The carrier density is estimated being n = $1.5\times10^{22}cm^{-3}$ at 300 K if one-band model is simply adopted. It is nearly an order higher than that of LaFeAsO with n $\sim 1.8\times10^{21}cm^{-3}$ at 300 K obtained by same method. Optical measurement also indicates a quite large plasma frequency, ω_p $\sim$ 1.5 eV.[32] The large carrier number for $SrFe_2As_2$ indicate that it is a good metal. Below 200 K, the Hall coefficient increases slightly to a positive value, and then drops dramatically to a very large negative value. The absolute value of R_H at 2 K is about 35 times larger than that at 300 K. The dramatic change reflects the reconstruction of Fermi surface after SDW transition. The band calculation show that there are 3 hole pockets around Γ point and 2 electron pockets around M point[11]. The experiments seem to indicate that, upon cooling below the SDW transition temperature, hole pockets are almost fully gapped while the electron pockets are partially gapped. Therefore, at low temperatures, the R_H reflect mainly the the un-gapped electron density around M point, which is significantly small in comparison with its initial value above 200K.

In addition to parent $SrFe_2As_2$, the anisotropy of resistivity and upper critical field for

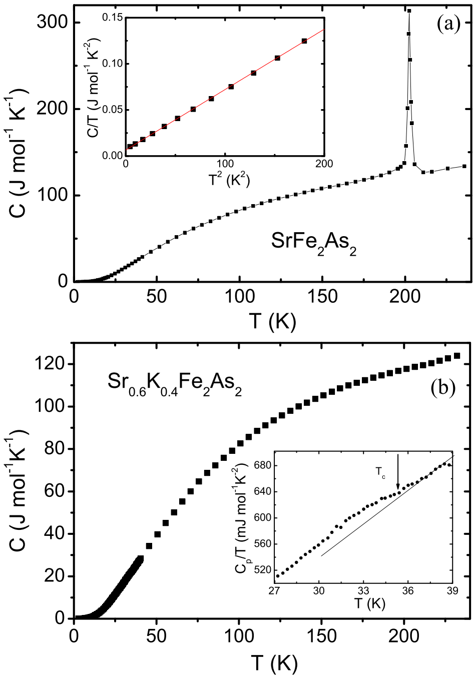

FIG. 4: (Color online) (a) Temperature dependence of specific heat C for $SrFe_2As_2$. Inset: T^2 dependence of C/T in low temperatures. (b)Temperature dependence of specific heat C for $Sr_{0.6}K_{0.4}Fe_2As_2$. Inset: C/T around superconducting transition.

single crystals $A_{0.6}K_0.4Fe_2As_2$ (A=Sr, Ba) is also investigated. Figure 6(a) shows the temperature dependence of the in-plane resistivity in zero field for $Sr_{0.6}K_{0.4}Fe_2As_2$ and $Ba_{0.6}K_{0.4}Fe_2As_2$ crystals. ρ_{ab} decreases with decreasing temperature and shows a downward curvature for $Sr_{0.6}K_{0.4}Fe_2As_2$, consistent with the polycrystal sample. With further decreasing temperature, an extremely sharp superconducting transition at 35.5 K with transition width about 0.3 K is observed, indicating high homogeneity of the sample. A sharp superconducting transition for $Ba_{0.6}K_{0.4}Fe_2As_2$ is also observed with T_c=38 K, slightly higher than that of $Sr_{0.6}K_{0.4}Fe_2As_2$. The anisotropic resistivity ρ_c/ρ_{ab} in normal state for $Sr_{0.6}K_{0.4}Fe_2As_2$ is found to be 21, much lower than that of parent $SrFe_2As_2$.

Figure 6(b) and figure 6(c) show ρ_{ab}(T) for $Sr_{0.6}K_{0.4}Fe_2As_2$ in external magnetic fields up to 14 T along c-axis and within ab plane, respectively. We can see the superconducting transition is broadened slightly in magnetic fields up to 14 T. The behavior is different from polycrystalline LaFeAsO where the superconducting transition is broadened strongly

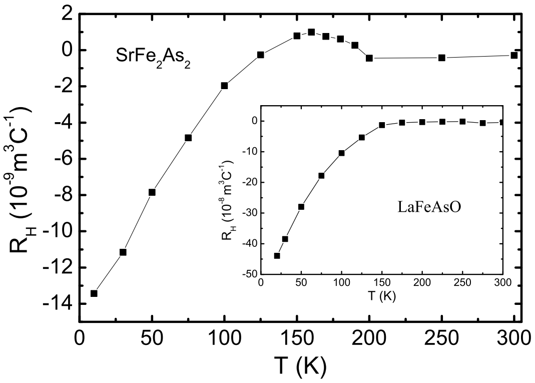

FIG. 5: (Color online) Temperature dependence of Hall coefficient for $SrFe_2As_2$. For comparison, the temperature dependence of Hall coefficient of LaFeAsO is shown in the inset.

in magnetic fields.[33] Figure 6(d) shows H_{c2}-T_c curves for both H‖ab and H‖c, respectively, where T_c is adopted by a criterion of 90% of normal state resistivity. The curves $H_{c2}(T)$ are very steep with slopes $-dH_{c2}^{ab}$ /dT $|_{T_c}=7.57$ T/K for H‖ab and $-dH_{c2}^{ab}/dT|_{T_c}=3.80$ T/K for H‖c. This indicates the upper critical fields is extremely high for $Sr_{0.6}K_{0.4}Fe_2As_2$. Using the Werthamer-Helfand-Hohenberg formula[34] $H_{c2}(0)=-0.69(dH_{c2}/dt)T_c$ and taking $T_c=35.5$K, the upper critical fields are: $H_{c2}^{ab}=185.4$ T and $H_{c2}^{c}=93.1$ T, respectively. The anisotropy ratio $\gamma=H_{c2}^{ab}/H_{c2}^{c}\approx2.0$.[20] The value of γ is close to that of $Ba_{0.55}K_{0.45}Fe_2As_2$ with γ between 2.5 to 3.5. It is lower than that of F-doped NdFeAsO[35] with $\gamma \approx$ 4.3-4.9, and much lower than high T_c cuprates, for example $\gamma \approx$ 7-10 for YBCO.[36] The lower values of ρ_c/ρ_{ab} and γ indicate that the inter-plane coupling in $Sr_{0.6}K_{0.4}Fe_2As_2$ is relative strong.

To summarize, $SrFe_2As_2$ and $A_{0.6}K_{0.4}Fe_2As_2$(A=Sr, Ba) single crystals were prepared by flux method. The angular dependence of in-plane resistivity was measured for $SrFe_2As_2$. A 2-fold symmetry of oscillations in AMR is observed at low temperatures which possible indicate a stripe-type spin structure below SDW temperature. In K doped $A_{0.6}K_{0.4}Fe_2As_2$(A=Sr. Ba), the SDW instability is suppressed and instead superconductivity appears with T_c above 35 K. The upper critical field is rather high with $H_{c2}^{ab}=185.4$ T, while its anisotropy is rather low. The inter-plane coupling may play an important role in this material.

Acknowledgments

We acknowledge Z. D. Wang, T. Xiang and Z. Fang for helpful discussions, and Q. M. Meng in experiments. This work is supported by the National Science Foundation of China,

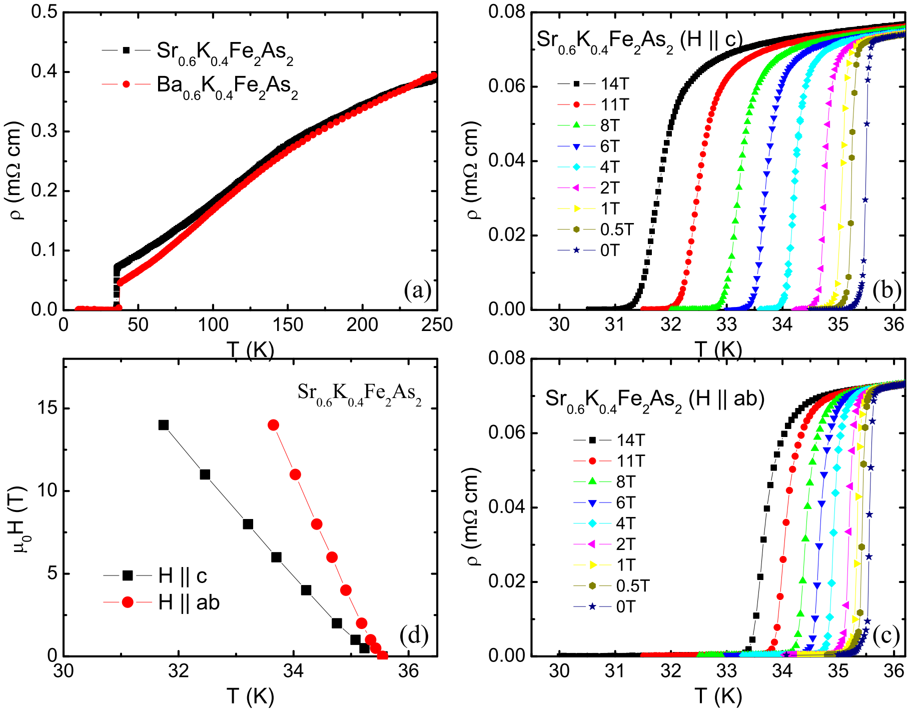

FIG. 6: (Color online) (a) Temperature dependence of the in-plane electrical resistivity for $Sr_{0.6}K_{0.4}Fe_2As_2$ and $Ba_{0.6}K_{0.4}Fe_2As_2$ in zero field, respectively. (b) and (c) Temperature dependence of the in-plane electrical resistivity for $Sr_{0.6}K_{0.4}Fe_2As_2$ at fixed fields up to 14T for H || c and H || ab, respectively. (d)H_{c2}(T) plot for H || c(closed square) and H || ab(open circle) , respectively.

the Knowledge Innovation Project of the Chinese Academy of Sciences, and the 973 project of the Ministry of Science and Technology of China.

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